

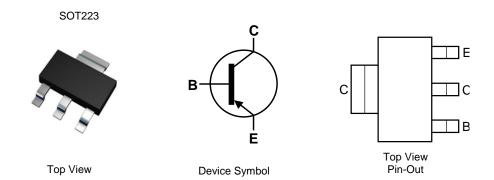
150V PNP HIGH VOLTAGE TRANSISTOR IN SOT223

Features

- BV_{CEO} > -150V
- I_C = -1A Continuous Current
- I_{CM} = -2A Peak Pulse Current
- Complementary NPN Type: DIODES™ FZT655
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208[®]
- Weight: 0.112 grams (Approximate)



Ordering Information (Note 4)

Part Number	Compliance	Paakaga	kage Marking Reel Size (inch		el Size (inches) Tape Width (mm)		Packing	
Part Number	Compliance	Package	Warking	Reel Size (Iliches)	Tape Width (mm)	Qty.	Carrier	
FZT755TA	Standard	SOT223	FZT755	7	12	1,000	Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

FZT ≥ 755 ≥

SOT223

FZT 755 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 2= 2022) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-150	V
Collector-Emitter Voltage	V _{CEO}	-150	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	I _{CM}	-2	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3		
Power Dissipation	(Note 6)		2	l w	
Power Dissipation	(Note 7)	P _D	1.6	VV	
	(Note 8)		1.2		
	(Note 5)		41.7		
Thermal Resistance, Junction to Ambient	(Note 6)	D	62.5	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	78.1	C/VV	
	(Note 8)		104		
Thermal Resistance, Junction to Leads (Note 9)		$R_{\theta JL}$	12.9	°C/W	
Operating and Storage Temperature Range	T _{J.} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 10)

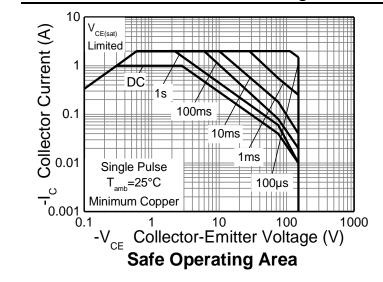
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

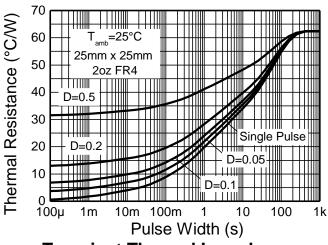
Notes:

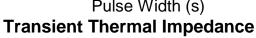
- 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
- 9. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

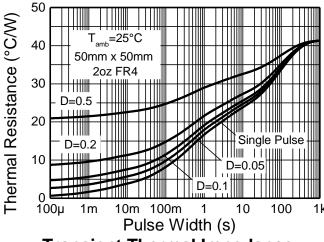


Thermal Characteristics and Derating Information

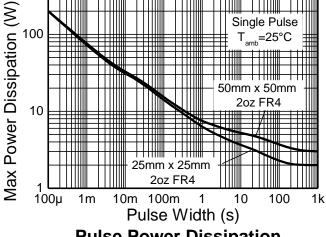




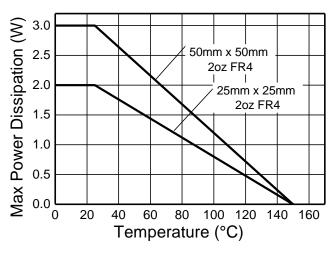




Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

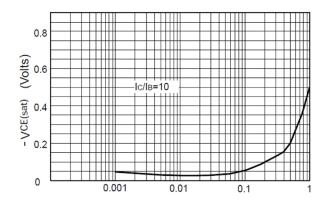
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-150	-	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-150	-	-	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-	-	V	$I_E = -100 \mu A$
Collector Cut-Off Current	I _{CBO}	=	-1	-100	nA	V _{CB} = -125V
Emitter Cut-Off Current	I _{EBO}	-	-1	-100	nA	V _{EB} = -6V
Collector-Emitter Saturation Voltage (Note 11)	1/	-	-	-0.5 -0.5	>	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(sat)}$					$I_C = -1A$, $I_B = -200mA$
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	_	-	-1.1	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	_	ï	-1.0	V	$I_C = -500 \text{mA}, V_{CE} = -5 \text{V}$
		50		-		$I_C = -10 \text{mA}, V_{CE} = -5 \text{V}$
DC Current Gain (Note 11)	h _{FE}	50	_	300	_	$I_C = -500 \text{mA}, V_{CE} = -5 \text{V}$
		20		-		$I_C = -1A$, $V_{CE} = -5V$
Current Gain-Bandwidth Product	fτ	30	_	-	MHz	I _C = -10mA, V _{CE} = -20V, f = 20MHz
Output Capacitance	C _{obo}	_	-	20	pF	V _{CB} = -10V, f = 1MHz

Note:

11. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

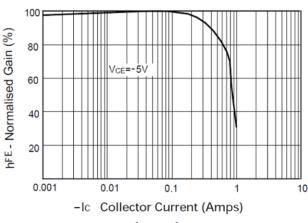


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

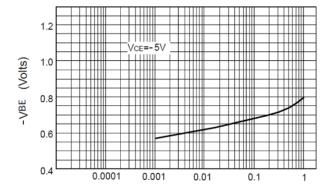


-lc Collector Current (Amps)

VCE(sat) v IC

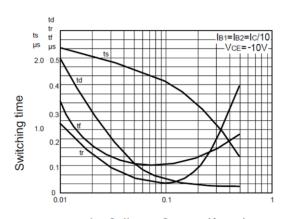


hfe v lc



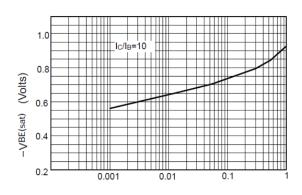
-Ic Collector Current (Amps)

VBE(on) v IC



-lc Collector Current (Amps)

Switching Speeds



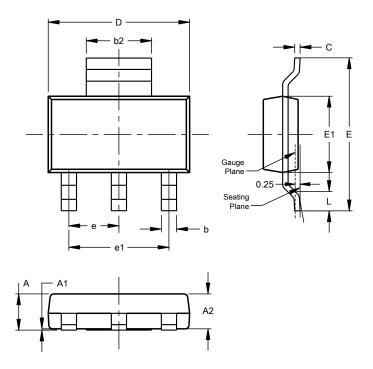
-Ic Collector Current (Amps)

VBE(sat) v IC



Package Outline Dimensions

Please see https://www.diodes.com/design/support/packaging/diodes-packaging/ for the latest version.

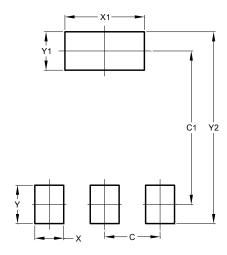


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see https://www.diodes.com/design/support/packaging/diodes-packaging/ for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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